2SC4466

**Preliminary** 

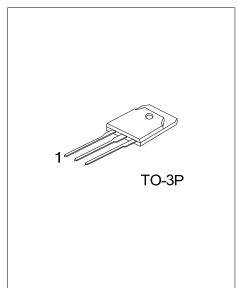
NPN EPITAXIAL SILICON TRANSISTOR

# SILICON NPN TRIPLE DIFFUSED PLANAR TRANSISTOR

#### DESCRIPTION

The UTC 2SC4466 is a silicon NPN triple diffused planar transistor, it uses UTC's advanced technology to provide the customers with high DC current gain and high collector-base breakdown voltage, etc.

The UTC 2SC4466 is suitable for audio and general purpose, etc.



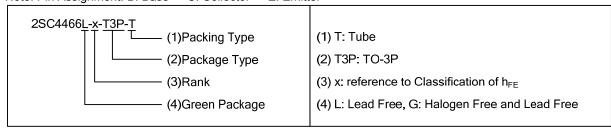
#### **FEATURES**

- \* High DC current gain
- \* High collector-base breakdown voltage

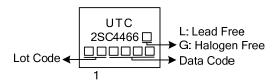
#### **ORDERING INFORMATION**

Ordering	Number	Doolsono	Pin Assignment		Pin Assignment B		Deelsing
Lead Free	Halogen Free	Package	1	2	3	Packing	
2SC4466L-x-T3P-T	2SC4466G-x-T3P-T	TO-3P	В	С	Е	Tube	

Note: Pin Assignment: B: Base C: Collector E: Emitter

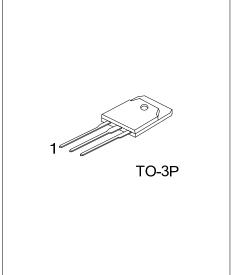


#### **MARKING**



Chunnithing 1688.com www.unisonic.com.tw 1 of 3 QW-R214-019.c





## ■ ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub>=25°C)

PARAMETER	SYMBOL	RATINGS	UNIT
Collector-Base Voltage	$V_{CBO}$	120	V
Collector-Emitter Voltage	$V_{CEO}$	80	V
Emitter-Base Voltage	$V_{EBO}$	6	V
Collector Current	Ic	6	Α
Base Current	I <sub>B</sub>	3	Α
Collector Power Dissipation (T <sub>C</sub> =25°C)	Pc	60	W
Junction Temperature	TJ	150	°C
Storage Temperature	T <sub>STG</sub>	-55 ~150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

## ■ ELECTRICAL CHARACTERISTICS (T<sub>A</sub> =25°C)

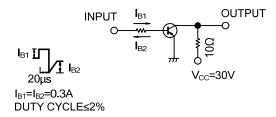
PARAMETER		SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector Cut-Off Current		I <sub>CBO</sub>	V <sub>CB</sub> =120V			10	μΑ
Emitter Cut-Off Current		I <sub>EBO</sub>	V <sub>EB</sub> =6V			10	μΑ
Collector-Emitter Breakdown Voltage		BV <sub>CEO</sub>	I <sub>C</sub> =50mA	80			V
DC Current Gain		h <sub>FE</sub>	V <sub>CE</sub> =4V, I <sub>C</sub> =2A	50		180	
Collector-Emitter Saturation Voltage		V <sub>CE(SAT)</sub>	I <sub>C</sub> =2A, I <sub>B</sub> =0.2A			1.5	V
Current Gain Bandwidth Product		f⊤	V <sub>CE</sub> =12V, I <sub>E</sub> =-0.5A		20		MHz
Output Capacitance		Cob	V <sub>CB</sub> =10V, f=1MHz		110		рF
Switching time	Turn-on time	t <sub>ON</sub>	V <sub>CC</sub> =30V, R <sub>L</sub> =10Ω, I <sub>C</sub> =3A, I <sub>B1</sub> =0.3A I <sub>B2</sub> =0.3A		0.16		μS
	Storage time	ts			2.60		μS
	Fall time	t <sub>F</sub>			0.34		μS

## ■ CLASSIFICATION OF h<sub>FE</sub>

RANK	0	Р	Y
RANGE	50~100	70~140	90~180



### **■ TEST CIRCUIT**



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